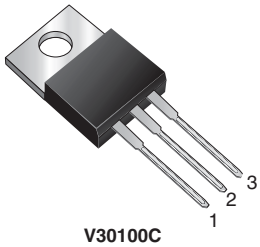
Dual High Voltage Trench MOS Barrier Schottky Rectifier

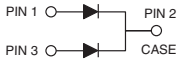
Ultra Low V_F = 0.455 V at I_F = 5 A

TMBS®

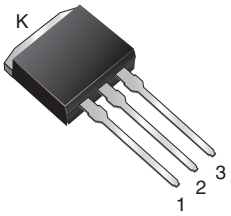
TO-220AB



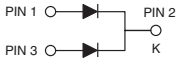
V30100C



TO-262AA



VI30100C



FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Low thermal resistance
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

RoHS COMPLIANT
HALOGEN FREE

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2 x 15 A
V_{RRM}	100 V
I_{FSM}	160 A
V_F at I_F = 15 A	0.63 V
T_J max.	150 °C
Package	TO-220AB, TO-262AA
Diode variation	Common cathode

MECHANICAL DATA

Case: TO-220AB and TO-262AA
Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102
M3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs max.

MAXIMUM RATINGS (T_A = 25 °C unless otherwise noted)

PARAMETER		SYMBOL	V30100C	VI30100C	UNIT
Max. repetitive peak reverse voltage		V_{RRM}	100		V
Max. average forward rectified current (fig. 1)	per device	$I_{F(AV)}$	30		A
	per diode		15		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I_{FSM}	160		A
Voltage rate of change (rated V_R)		dV/dt	10 000		V/µs
Operating junction and storage temperature range		T_J, T_{STG}	-40 to +150		°C

ELECTRICAL CHARACTERISTICS (T_A = 25 °C unless otherwise noted)						
PARAMETER	**TEST CONDITIONS**		**SYMBOL**	**TYP.**	**MAX.**	**UNIT**
Instantaneous forward voltage per diode	I_F = 5 A	T_A = 25 °C	V_F (1)	0.516	-	V
	I_F = 7.5 A			0.576	-	
	I_F = 15 A			0.734	0.80	
	I_F = 5 A	T_A = 125 °C		0.455	-	
	I_F = 7.5 A			0.522	-	
	I_F = 15 A			0.627	0.68	
Reverse current per diode	V_R = 70 V	T_A = 25 °C	I_R (2)	7.2	-	µA
		T_A = 125 °C		8.0	-	mA
	V_R = 100 V	T_A = 25 °C		65	500	µA
		T_A = 125 °C		20	35	mA

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T_A = 25 °C unless otherwise noted)				
PARAMETER	**SYMBOL**	**V30100C**	**VI30100C**	**UNIT**
Typical thermal resistance per diode	$R_{\theta JC}$	2.5		°C/W

ORDERING INFORMATION (Example)					
PACKAGE	**PREFERRED P/N**	**UNIT WEIGHT (g)**	**PACKAGE CODE**	**BASE QUANTITY**	**DELIVERY MODE**
TO-220AB	V30100C-M3/4W	1.88	4W	50/tube	Tube
TO-262AA	VI30100C-M3/4W	1.45	4W	50/tube	Tube

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

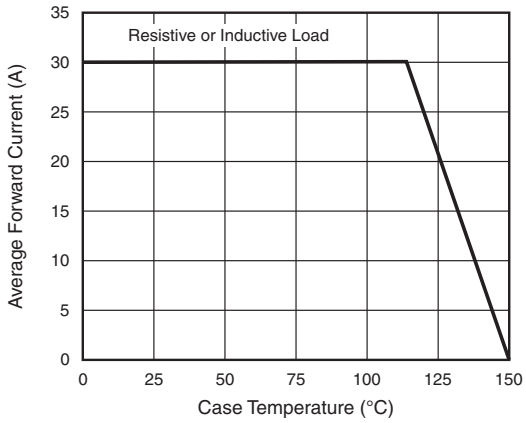


Fig. 1 - Forward Current Derating Curve

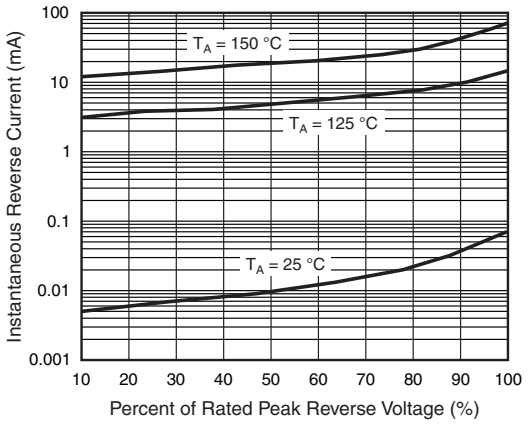


Fig. 4 - Typical Reverse Characteristics Per Diode

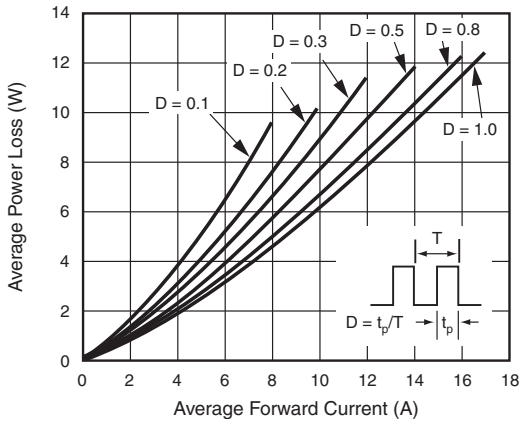


Fig. 2 - Forward Power Loss Characteristics Per Diode

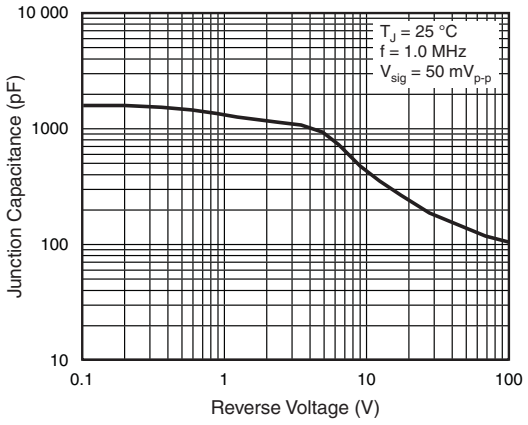


Fig. 5 - Typical Junction Capacitance

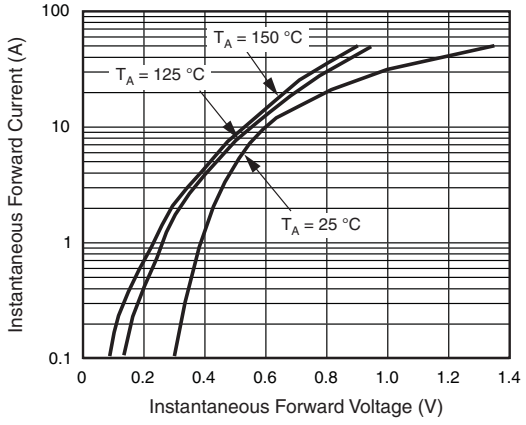


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

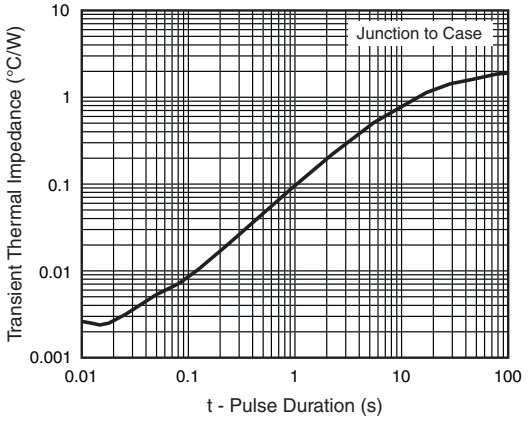
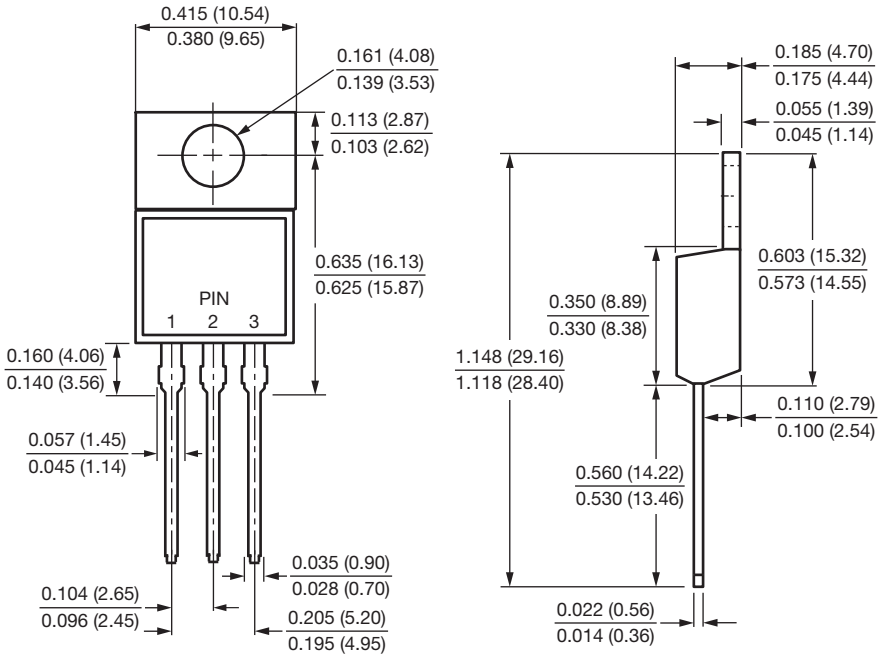


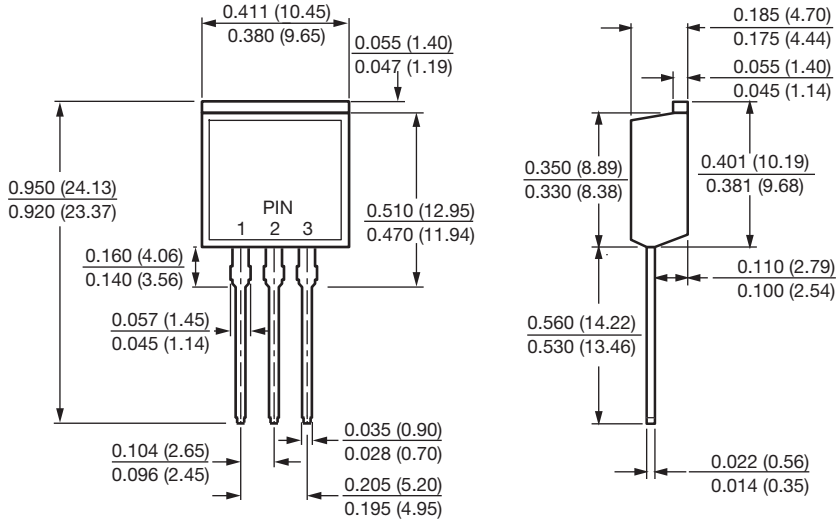
Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-220AB



TO-262AA



Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, “Vishay”), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay’s knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer’s responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer’s technical experts. Product specifications do not expand or otherwise modify Vishay’s terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.